

SANYO Semiconductors **DATA SHEET**

Monolithic Digital IC

LB8681CL—Constant Current Driver IC with H-bridge × 1.5 Channel

Overview

The LB8681CL is a low-voltage, low-saturation 1.5-channel constant current forward/reverse driver IC provided in a miniature package suitable for use in cell phone cameras. The LB8681CL can be driven directly from a microcontroller and is optimal for control of the voice coil motors used for shutter and aperture control in cell phone cameras.

Features

- Supports low-voltage drive. (2.2V or more)
- Ultraminiature package (ECSP2828-10)

Functions

- Constant current control ($I_{OUT} = 100 \text{mA}$ at $R_F = 2\Omega$)
- Built-in thermal protection circuit
- Built-in reference voltage (0.2V typical)
- Built-in spark killer diode

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	
Maximum supply voltage	V _{CC} max		-0.3 to +8.0	V
Output voltage	V _{OUT} max	OUT1, OUT2, OUT3	V _{CC} + VSF	V
Input voltage	V _{IN} max	IN1, IN2, IN3	-0.3 to +8.0	V
Ground pin source current	IGND	Per channel	400	mA
Allowable power dissipation	Pd max	When mounted on a circuit board *	450	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-40 to +150	°C

^{*} Specified circuit board : 20.0 × 10.0 × 0.8mm³, paper-phenol

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Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		2.2 to 7.5	V
High-level input voltage	VIH	IN1,IN2,IN3	1.8 to 7.5	V
Low-level input voltage	V _{IL}		-0.3 to 0.7	V

Electrical Characteristics at Ta = 25°C, $V_{CC} = 3.3V$

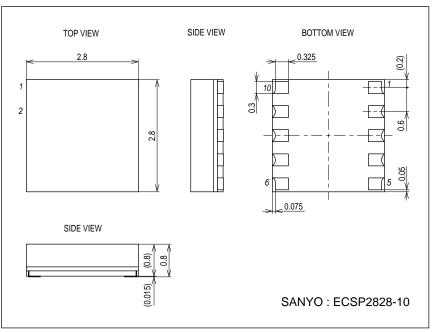
Parameter	Cumbal	Conditions		Ratings		
Parameter	Symbol	Conditions	min	typ	max	Unit
Supply current I _{CC} 0 IN1 =		IN1 = IN2 = IN3 = 0V		0.1	1	μΑ
	I _{CC} 1	IN1, IN2, or IN3 = 3V		13.9	18	mA
Output saturation voltage	V _{OUT} 1	IN1, IN2, or IN3 = 3V, I _{OUT} = 100mA		0.20	0.32	V
	V _{OUT} 2	IN1, IN2, or IN3 = 3V, I _{OUT} = 200mA*		0.41	0.62	V
Output constant current	lOUT1	Between REF and GND : 2Ω 95		100	105	mA
	I _{OUT2}	Between REF and GND : $1\Omega^*$	190	200	210	mA
Input current	I _{IN}	V _{IN} = 3V		40	60	μΑ
Spark killer diode						
Reverse current	IS(leak)				1	μΑ
Forward voltage	VSF	I _{OUT} = 200mA*			1.7	V

^{*} Design guarantee: These characteristics are design targets and are not measured.

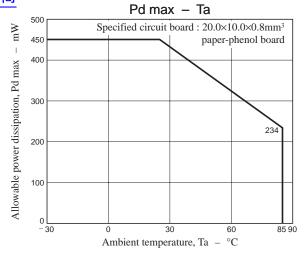
Package Dimensions

unit: mm (typ)

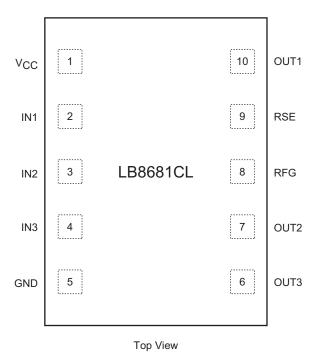
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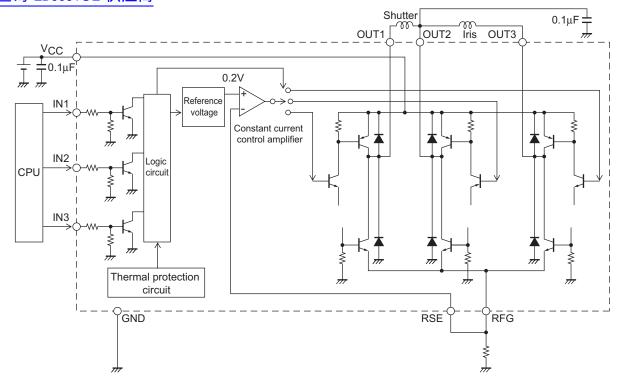
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Pin Assignment



Biogk_Biogram 供应商



[Constant current formula] $IOUT = 0.2 \div RF$

When V_{CC} is high, the 0.01µF capacitor may be inserted between OUT and OUT.

Truth Table

Input		Output			Notes		
IN1	IN2	IN3	OUT1	OUT2	OUT3	Notes	
	Low	Low	-	-	-	Standby	
1	High	Low	High	Low	-	Shutter	Forward
Low	Low	High	Low	High	-		Reverse
	High	High	Low	High	-		
	Low	Low	-	-	-	- Aperture -	Off
High	High	Low	-	Low	High		Forward
	Low	High	-	High	Low		Reverse
	High	High	-	High	Low		

Note : "-" indicates the output off state. (high-impedance)

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